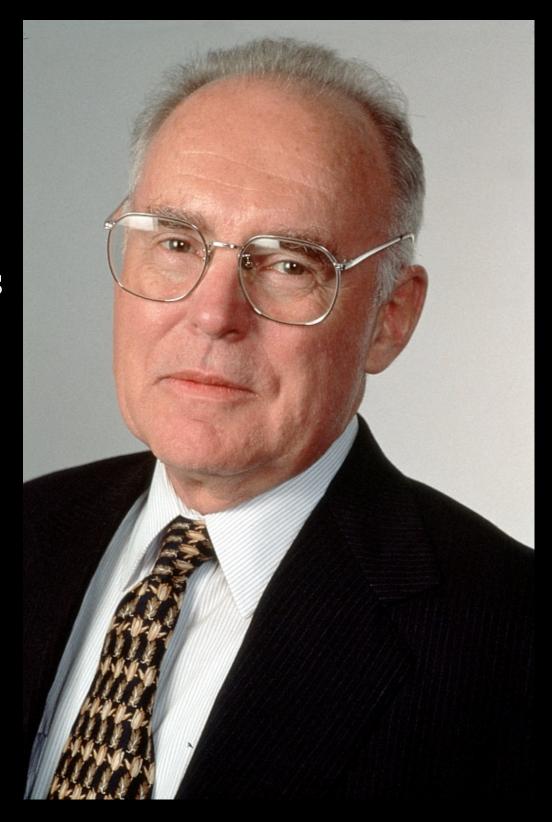
# COMPUTER ORGANISATION AND ARCHITECTURE

MOORE LAW

# MOORE'S LAW

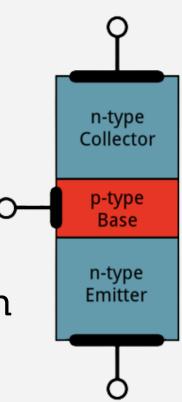
Moore's law was initially published in Electronics magazine in 1965, when Moore was a founding member of Fairchild Semiconductor and head of research. Moore's law states that the number of components on a computer chip doubles every two years. Moore anticipated that every two years, the number of transistors on a single square inch of an integrated circuit chip would double.

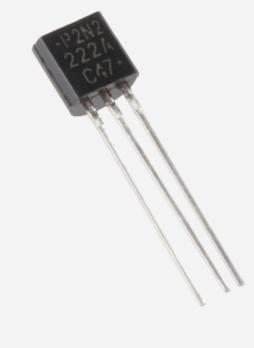
Moore's law is closely related to MOSFET scaling, as the rapid scaling and miniaturization of MOSFETs is the key driving force behind Moore's law. Mathematically, Moore's Law predicted that transistor count would double every 2 years due to shrinking transistor dimensions and other improvements.



#### **TRANSISTORS**

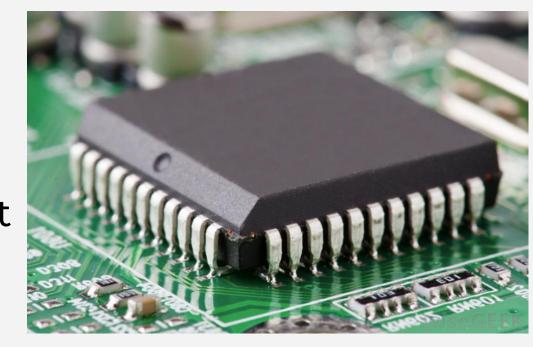
- A transistor is a three-terminal, bipolar, current-controlled semiconductor device with three parts: Emitter, Base, and Collector. The emitter zone is strongly doped, whereas the collector region has a large volume with medium doping levels.
- Transistor was invented in the late 1947s, with Silicon Atom as the primary production component.





## INTEGRATED CIRCUIT (IC)

- Integrated Circuit (IC) was created by assembling a large number of transistors on a single chip.
- Modern Digital Electronics has been transformed by the introduction of the Metal Oxide Semiconductor Field Effect Transistor (MOSFET) and the rapid development of ICs that are geometrically smaller, quicker, and less expensive.



10 µm - 1971

6 µm - 1974

3 µm - 1977

1.5 µm - 1981

1 µm - 1984

800 nm - 1987

600 nm - 1990

350 nm - 1993

250 nm - 1996

180 nm - 1999

130 nm - 2001

90 nm - 2003

65 nm - 2005

45 nm - 2007

32 nm - 2009

22 nm - 2012

14 nm - 2014

10 nm - 2016

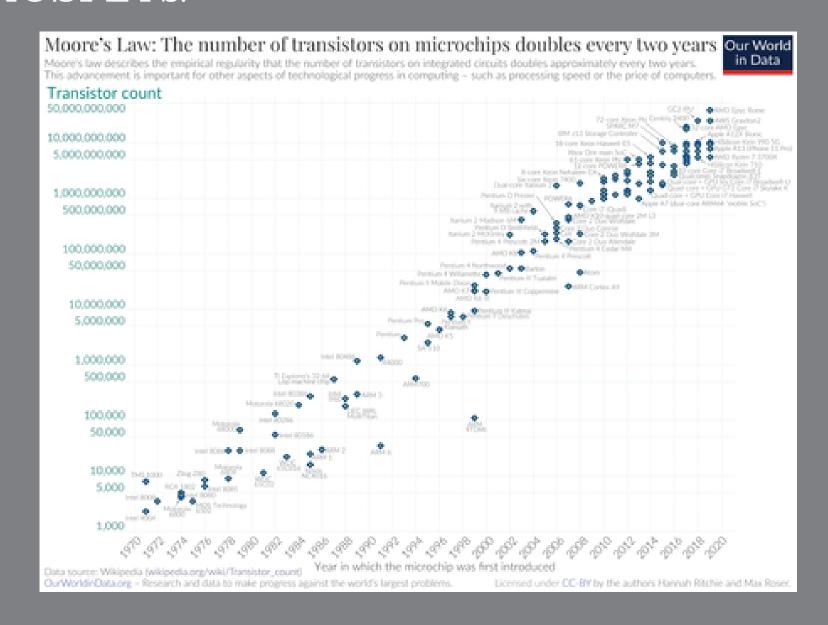
7 nm - 2018

5 nm - 2020

## PREDICTION VS REALITY

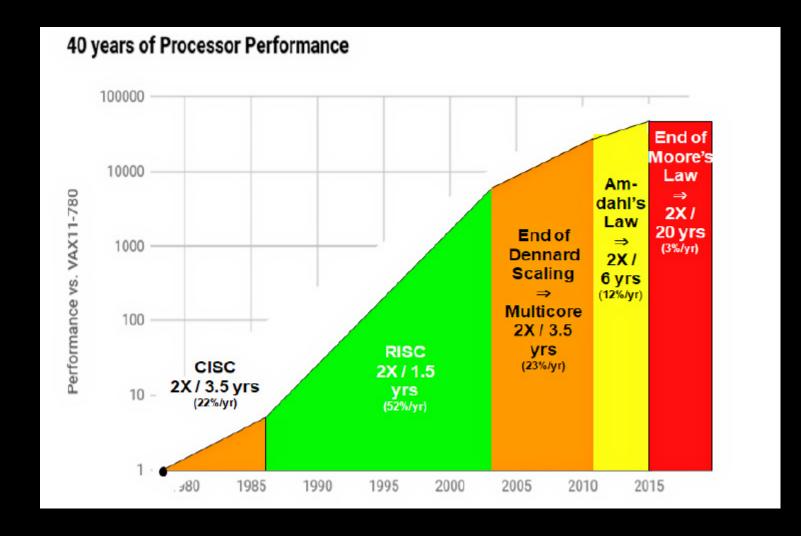
Since the prediction made in 1965 to till date, the world Electronics community has almost obeyed the law.

The following data depicts the temporal distribution of size of MOSFETs.



# STATISTICS

	Introduction Date	Clock Speeds	Bus Width	Number of Transistors	Addressable Memory	Virtuał Memory	Brief Description
4004	11/15/71	108 KHz	4 bits	2,300 (10 microns)	640 bytes		First microcomputer chip, Arithmetic manipulation
8008	4/1/72	108 KHz	8 bits	3,500	16 KBytes		Data/character manipulation
8080	4/1/74	2 MHz	8 bits	6,000 (6 microns)	64 KBytes		10X the performance of the 8008
8086	6/8/78	5 MHz 8 MHz 10 MHz	16 bits	29,000 (3 microns)	1 Megabyte		10X the performance of the 8080
8088	6/1/79	5 MHz 8 MHz	8 bits	29,000 (3 microns)			Identical to 8086 except for its 8-bit external bus
80286	2/1/82	8 MHz 10 MHz 12 MHz	16 bits	134,000 (1.5 microns)	16 Megabytes	l gigabyte	3-6X the performance of the 8086
Intel386(TM)DX Microprocessor	10/17/85	16 MHz 20 MHz 25 MHz 33 MHz	32 bits	275,000 (1 micron)	4 gigabytes	64 terabytes	First X86 chip to handle 32-bit data sets
Intel386(TM)SX Microprocessor	6/16/88	16 MHz 20 MHz	16 bits	275,000 (1 micron)	4 gigabytes	64 terabytes	16-bit address bus enabled low-cost 32-bit processing
intel486(TM)DX Microprocessor	4/10/89	25 MHz 33 MHz 50 MHz	32 bits	1,200,000 (1 micron, .8 micron with 50 MHz)	4 gigabytes	64 terabytes	Level 1 cache on chip
Intel486(TM)SX Microprocessor	4/22/91	16 MHz 20 MHz 25 MHz 33 MHz	32 bits	1,185,000 (.8 micron)	4 gigabytes	64 terabytes	identical in design to Intel486(TM) DX but without math coprocessor
Pentium® Processor	3/22/93	60MHz 66MHz 75MHz 90MHz 100MHz 120MHz 133MHz 150MHz 166MHz	и і	3.1 million (.8 micron)	4 gigabytes	64 terabytes	superscaler architecture brought 5X the performance of the 33-MHz Intel486 DX processor



1971: 2300 Transistors in Intel 4004 Microprocessor.

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2019: 20 billion Transistors in Samsung V-Nand Chip.

2020: 26 billion Transistors in Water Scale Engine 2.

2021: 59 billion MOSFET AMD's instinct.

2022: 114 billion Apple's ARM based MI Ultra.

## SCALING

The reduction of all Geometric dimensions of a chip by a factor(s) where s is an integer is called Scaling.

#### **Geometric Scaling**

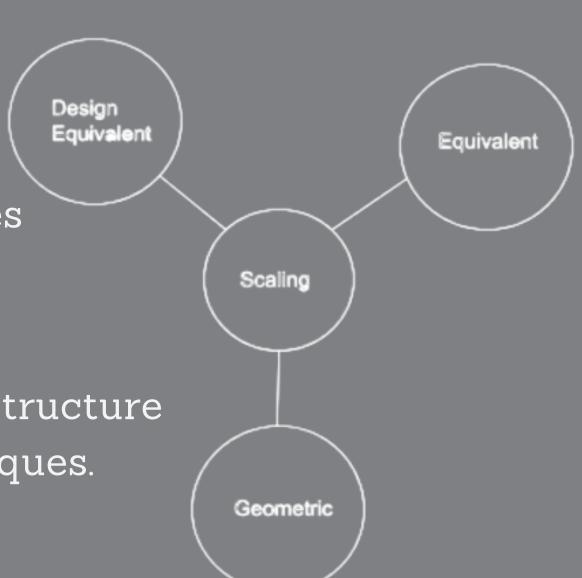
Shrinking of horizontal and vertical physical feature sizes of the on-chip logic.

## **Equivalent Scaling**

Continued Geometrical scaling to 3-dimensional device structure improvements and other non-geometrical process techniques.

## Design Equivalent Scaling

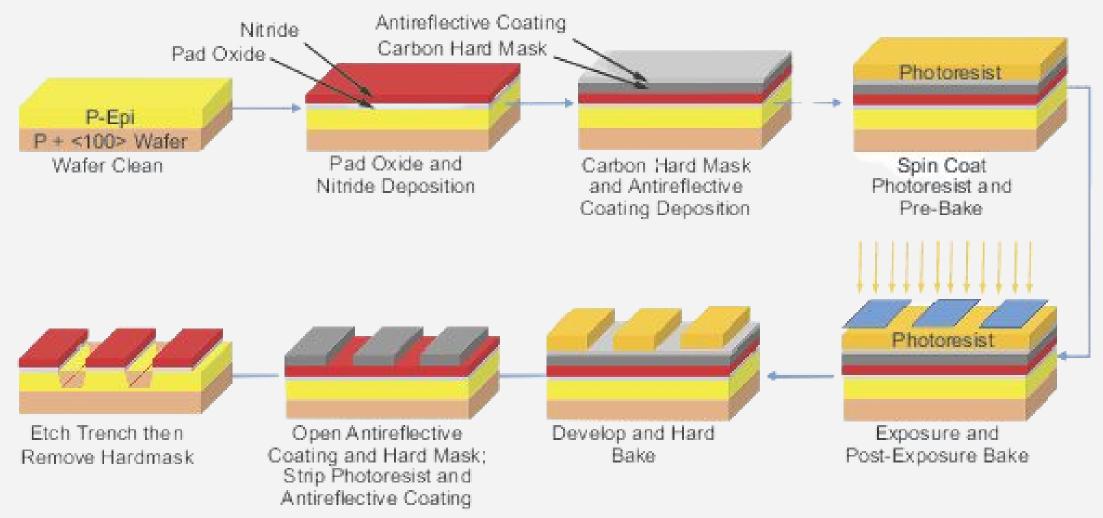
Design technologies that enable high performance, low power, high reliability, low cost, and high design productivity.



## LITHOGRAPHY

Semiconductor Lithography or Photolithography which literally means "Light-Stone-Write". Photolithography is a process used in microfabrication to transfer geometric patterns to a

film or substrate.



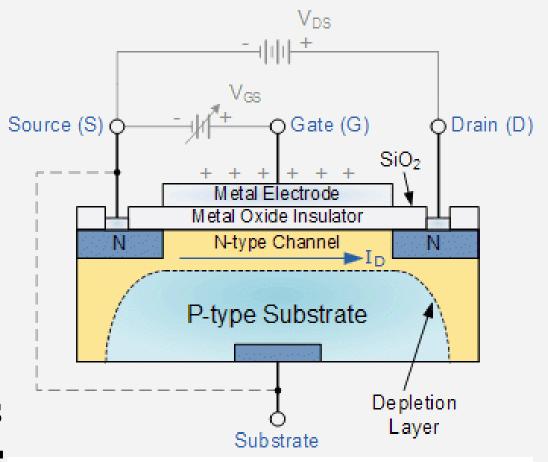
## HOW DID MOORE LAW TURNED TO REALITY?

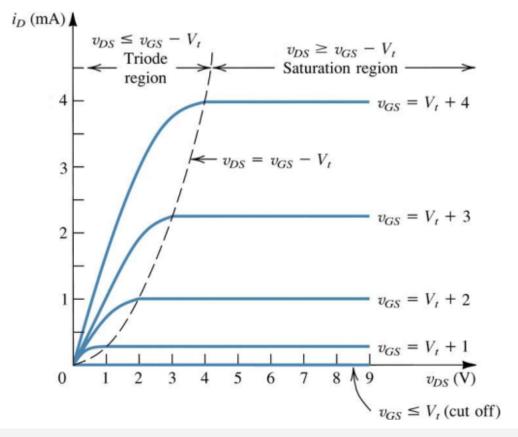
Moore's law isn't really a law in the legal sense or even a proven theory in the scientific sense. Many new types of transistors were designed after 1970 in order to improve efficiency, close existing loopholes, and manufacture more transistors onto the chip for better CPUs.

The developed versions with various parameters for upgrading bipolar junction transistors are listed below.

# MOSFET

- A Metal Oxide Semiconductor Field-Effect Transistor is a four-terminal device with four terminals: source (S), gate (G), drain (D), and body (B). The body of the MOSFET is connected to the source terminal, resulting in a three-terminal device similar to a field-effect transistor.
- The electrical fluctuations in the channel width, as well as the flow of carriers, determine the operation of a MOSFET (either holes or electrons). Charge carriers enter the channel through the source terminal and escape through the drain terminal.
- The voltage on an electrode called the gate, which is placed between the source and the drain, controls the width of the channel. An exceedingly thin coating of metal oxide separates it from the channel.





## **JFET**

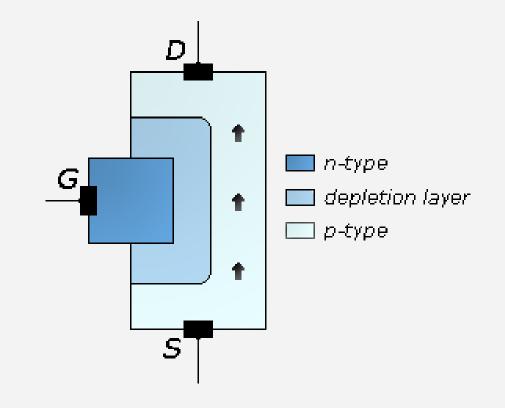
• One of the most basic varieties of field-effect transistor is the junction-gate field-effect transistor (JFET). JFETs are three-terminal semiconductor devices that can be used to produce amplifiers or as electronically controlled switches or resistors.

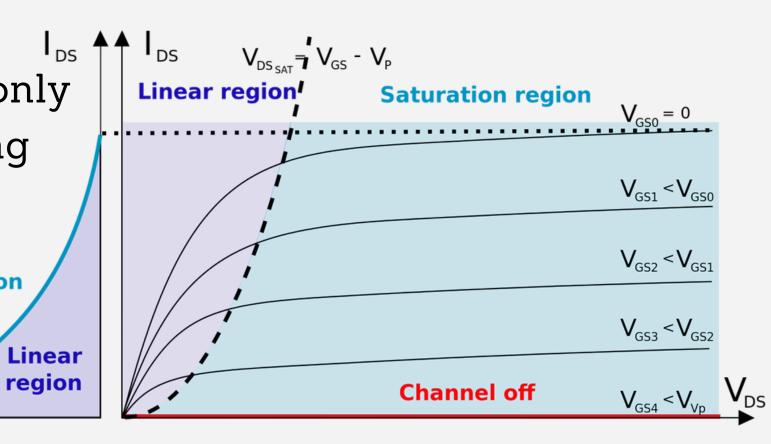
 JFETs, unlike bipolar junction transistors, are only voltage-controlled and do not require a biassing current.

**Saturation** 

region

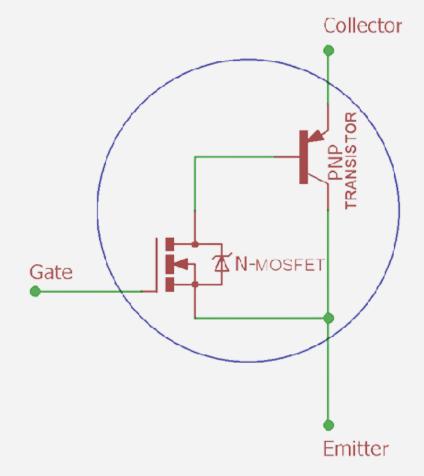
Channel



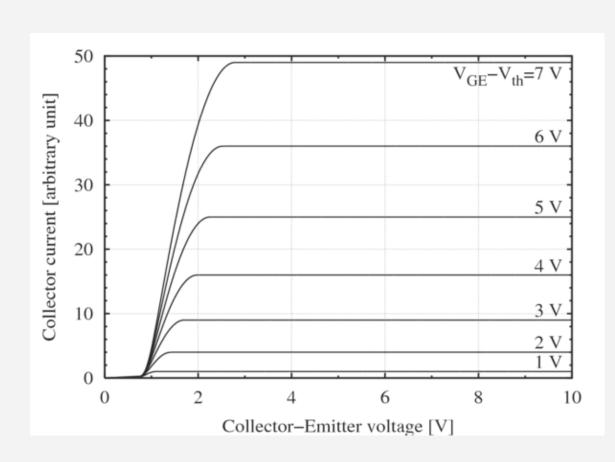


## **IGBT**

- The advent of the IGBT has accelerated the Power electronics industry, which has considerably contributed to huge Electronic and Electrical systems. Electronic BGTs functioned between OV-20V.

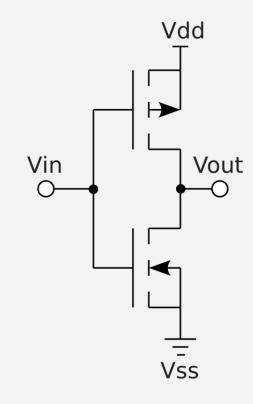


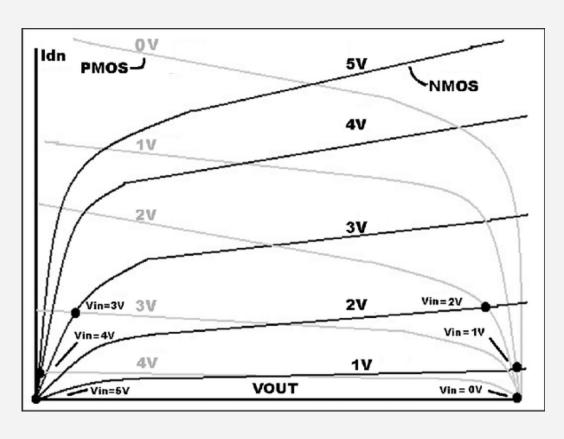
Equivalent Circuit



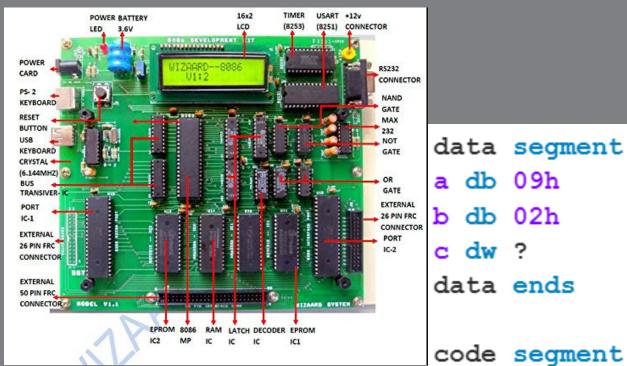
## **CMOS**

- Static power dissipation is nearly non-existent in a complementary MOS circuit. Only if the circuit really switches is power squandered. This enables the integration of more CMOS gates on an IC than is possible with NMOS or bipolar technology, resulting in much improved performance.
- P-channel MOS (PMOS) and N-channel MOS (NMOS) are complementary Metal Oxide Semiconductor transistors (NMOS).



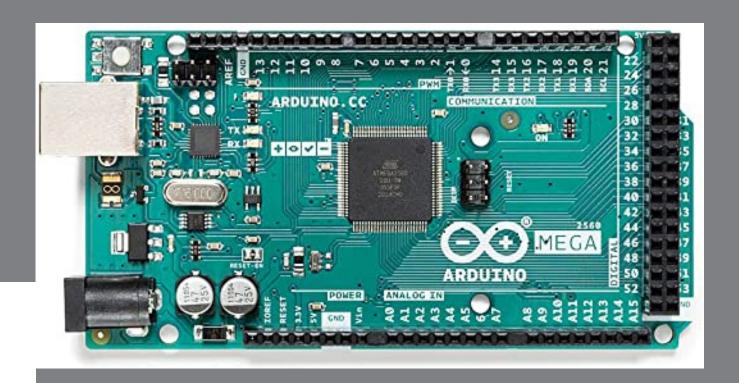


# A SIMPLE COMPARITIVE STUDY



```
a db 09h
b db 02h
c dw ?
data ends
code segment
assume cs:code,ds:data
start:
mov ax, data
mov ds,ax
mov al,a
mov bl,b
add al,bl
mov c,ax
int 3
code ends
end start
```

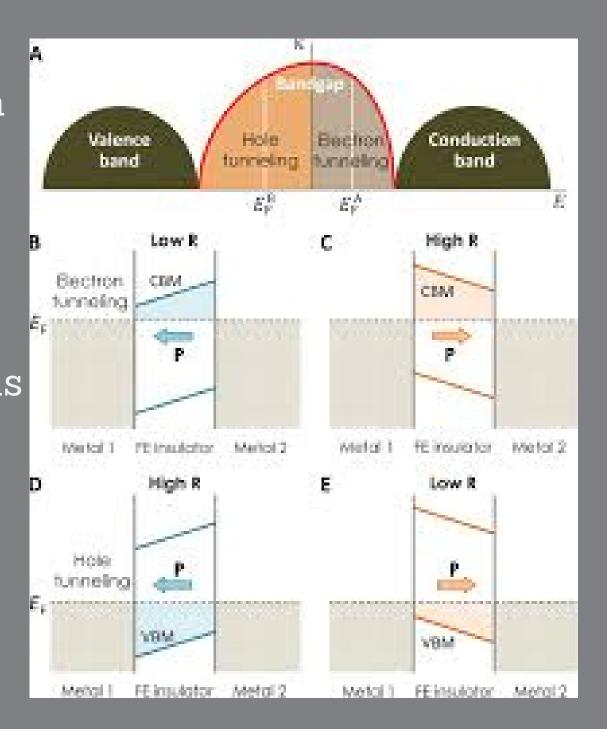
```
int a = 2;
int b = 7;
int sum;
sum = a + b;
```



#### ILL EFFECTS OF MOORE LAW

#### **Quantum Tunneling**

- The distance between the transistors' source and drain is so short that electrons jump over the barrier. As a result, rather of remaining in the desired logic gate, electrons flow continually from one gate to the next, thereby rendering the transistor inoperable.
- A dramatic redesign of the transistor, i.e. The FinFET, is the most popular nanoscale transistor, is required to overcome this. On three sides of the channel, the FinFET has gate dielectric. The gate-all-around MOSFET (GAAFET) structure, in comparison, offers even greater gate control.

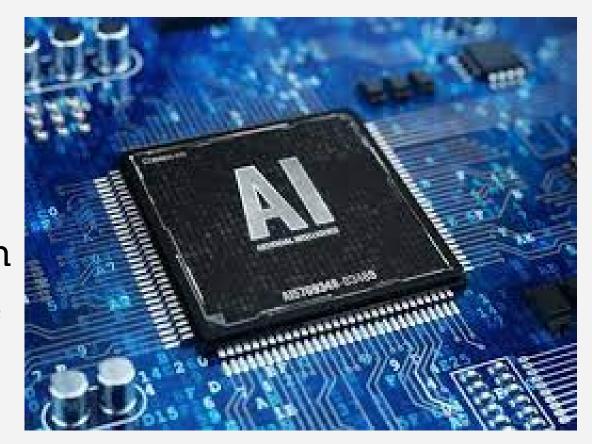


# EXTENDING MOORE LAW

Unfortunately, the rate of technological advancement has not decreased, and we are approaching the conclusion of Moore's Law. Many in the business are hesitant to make firm predictions about when the concept will become obsolete, but the general assumption is that it will happen between 2020 and 2025 — and no one appears to have a viable answer to this technological stumbling block.

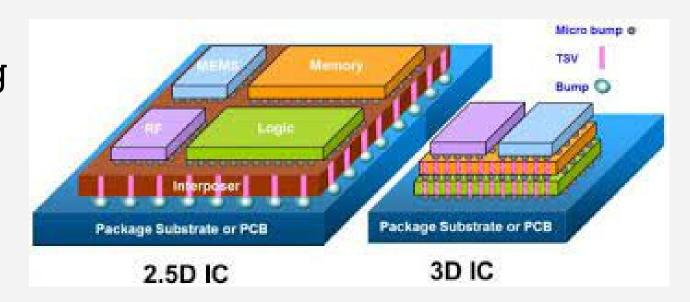
## **AICHIPS**

- Artificial intelligence chips (also known as AI hardware or AI accelerators) are specially built accelerators for ANN-based applications.
- Switching to a more ASIC-focused design might provide a stopgap solution and extend Moore's Law by about 10 years, but it would increase the von Neumann bottleneck in the industry. Modern circuits are capable of operating so quickly that the time it takes for information to move between chips wastes computation time.



# 3DICs

- Three-dimensional integrated circuits, in which many wafers are stacked on top of one other and linked vertically. Design engineers can lower the distance data has to travel while simultaneously reducing chip footprint by successfully integrating numerous ICs together. 3D integration covers a wide range of technologies, including 3D waferlevel packaging (3DWLP), 2.5D and 3D interposerbased integration, 3D stacked ICs (3D-SICs), monolithic 3D ICs, 3D heterogeneous integration, and 3D systems integration.
- This might extend the usefulness of existing computer technologies, allowing Moore's Law to continue to apply.



#### CONCLUSION

- When we look back at NASA's Apollo 11 mission and Neil Armstrong's success tale, we can see a tremendous growth in the quantity of transistors and a drop in their size. Again, Moore's law was only a forecast in 1965, and it is clear that the subsequent trend has followed it.
- Solutions to generic issue statements are headed towards the period of Industrial Revolution 4.0, often known as the Digital Revolution.
- Artificial Intelligence (AI), Machine Learning (ML), Deep Learning (DL), Internet Of Things (IoT), and other terms are used to describe these technologies. Such solutions frequently need advanced computational abilities and substantial power usage.
- Electronics such as Very-Large-Scale-Integration (VLASI), Very-Very-Large-Scale-Integration (VVLSI), and others are enabling more computing.